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		Applicati n Number	Not Yet Assigned
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		First Named Inventor	Philbert F. Marsh et al.
		Art Unit	Not Yet Assigned
		Examiner Name	Not Yet Assigned
Sheet 1 of 1	Attorney Docket Number	RTN2-152PUS	

OTHER PRIOR ART–NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
TT		ENOKI ET AL.; "Design and Characteristics of InGaAs/InP Composite-Channel HEFT's;" IEEE Transactions on Electron Devices, Vol. 42, No. 8, August 1995; 0018-9383/95; pages 413-418.	
TT		HOKE ET AL.; "Molecular Beam Epitaxial Growth and Device Performance of Metamorphic High Electron Mobility Transistor Structures Fabricated on GaAs Substrates;" J. Vac. Sci. Technol. B 17(3), May/June 1999; American Vacuum Society; 0734-211X/99/71(3)/1131/5; pages 1131-1135.	
TT		WHELAN ET AL.; "GaAs Metamorphic HEMT (MHEMT): An Attractive Alternative to InP HEMTs for High Performance Low Noise and Power Applications;" 2000 IEEE 0-7803-6320-5-00; pages 337-340.	
TT		deALAMO ET AL.; "Breakdown in Millimeter-Wave Power InP HEMT's: A Comparison with GaAs PHEMT's;" IEEE Journal of Solid-State Circuits, Vol. 34, No. 9, September 1999; 0018-9200/99; pages 1204-21.	

Examiner Signature		Date Considered	02/24
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.

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